

HCPL0600, HCPL0601, HCPL0611, HCPL0637, HCPL0638, HCPL0639 High Speed-10 MBit/s Logic Gate Optocouplers

Single Channel: HCPL0600, HCPL0601, HCPL0611
Dual Channel: HCPL0637, HCPL0638, HCPL0639

Features

- Compact SO8 package
- Very high speed-10 MBit/s
- Superior CMR
- Logic gate output
- Strobable output (single channel devices)
- Wired OR-open collector
- U.L. recognized (File # E90700)
- IEC60747-5-2 approved (VDE option)
– HCPL0600, HCPL0601, HCPL0611 only

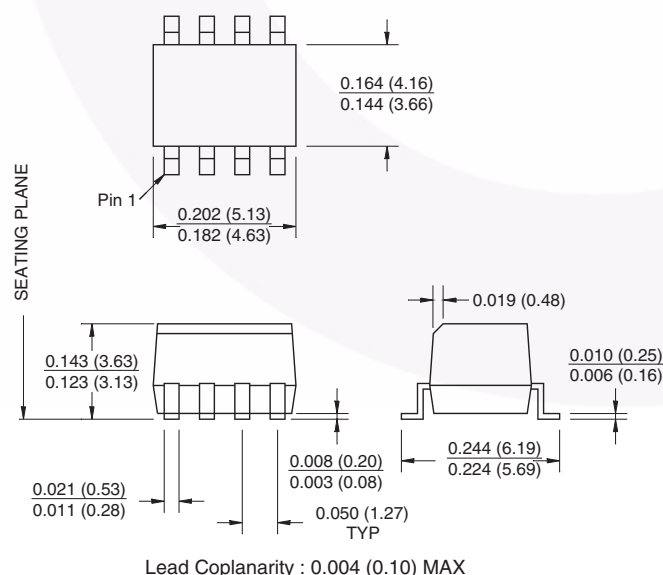
Applications

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5-volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer-peripheral interface

Description

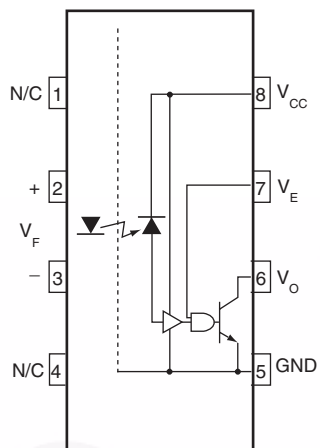
The HCPL06XX optocouplers consist of an AlGaAs LED, optically coupled to a very high speed integrated photo-detector logic gate with a strobable output (single channel devices). The devices are housed in a compact small-outline package. This output features an open collector, thereby permitting wired OR outputs. The HCPL0600, HCPL0601 and HCPL0611 output consists of bipolar transistors on a bipolar process while the HCPL0637, HCPL0638, and HCPL0639 output consists of bipolar transistors on a CMOS process for reduced power consumption. The coupled parameters are guaranteed over the temperature range of -40°C to +85°C. An internal noise shield provides superior common mode rejection.

Package Dimensions

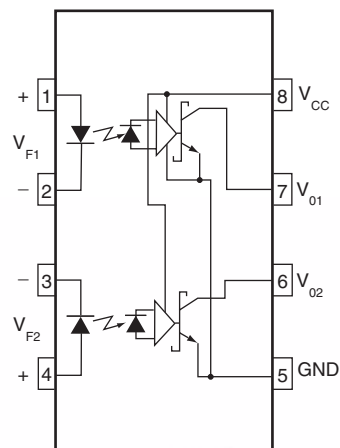


Note:

All dimensions are in inches (millimeters)



Single-channel circuit drawing
(HCPL0600, HCPL0601 and HCPL0611)



Dual-channel circuit drawing
(HCPL0637, HCPL0638 and HCPL0639)

Truth Table (Positive Logic)

Input	Enable	Output
H	H	L
L	H	H
H	L	H
L	L	H
H*	NC*	L*
L*	NC*	H*

*Dual channel devices or single channel devices with pin 7 not connected.
A 0.1 μ F bypass capacitor must be connected between pins 8 and 5. (See note 1)

Absolute Maximum Ratings (No derating required up to 85°C)

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter		Value	Units
T _{STG}	Storage Temperature		-40 to +125	°C
T _{OPR}	Operating Temperature		-40 to +85	°C
EMITTER				
I _F	DC/Average Forward Input Current (each channel)	Single Channel	50	mA
		Dual Channel		
V _E	Enable Input Voltage Not to exceed VCC by more than 500mV	Single Channel	5.5	V
V _R	Reverse Input Voltage (each channel)		5.0	V
P _I	Power Dissipation	Single Channel	45	mW
		Dual Channel		
DETECTOR				
V _{CC} (1 minute max)	Supply Voltage		7.0	V
I _O	Output Current (each channel)	Single Channel	50	mA
		Dual Channel	15	
V _O	Output Voltage (each channel)		7.0	V
P _O	Collector Output Power Dissipation	Single Channel	85	mW
		Dual Channel	85	

Recommended Operating Conditions

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter		Min.	Max.	Units
I _{FL}	Input Current, Low Level		0	250	μA
I _{FH}	Input Current, High Level		*6.3	15	mA
V _{CC}	Supply Voltage, Output		4.5	5.5	V
V _{EL}	Enable Voltage, Low Level	Single Channel only	0	0.8	V
V _{EH}	Enable Voltage, High Level	Single Channel only	2.0	V _{CC}	V
T _A	Operating Temperature		-40	+85	°C
N	Fan Out (TTL load)	Single Channel		8	TTL Loads
		Dual Channel		5	
R _L	Output Pull-up		330	4K	Ω

*6.3mA is a guard banded value which allows for at least 20% CTR degradation. Initial input current threshold value is 5.0mA or less

Electrical Characteristics (T_A = -40°C to +85°C unless otherwise specified.)

Individual Component Characteristics

Symbol	Parameter	Test Conditions	Min.	Typ.*	Max.	Unit
EMITTER						
V _F	Input Forward Voltage	I _F = 10mA T _A = 25°C			1.8 1.75	V
B _{VR}	Input Reverse Breakdown Voltage	I _R = 10μA	5.0			V
ΔV _F /ΔT _A	Input Diode Temperature Coefficient	I _F = 10mA		-1.5		mV/°C
DETECTOR						
I _{CCH}	High Level Supply Current	I _F = 0mA, V _{CC} = 5.5V V _E = 0.5 V	Single Channel		10	mA
			Dual Channel		15	
I _{CCL}	Low Level Supply Current	I _F = 10mA, V _{CC} = 5.5V V _E = 0.5 V	Single Channel		13	mA
			Dual Channel		21	
I _{EL}	Low Level Enable Current	V _{CC} = 5.5V, V _E = 0.5V	Single Channel		-1.6	mA
I _{EH}	High Level Enable Current	V _{CC} = 5.5V, V _E = 2.0V	Single Channel		-1.6	mA
V _{EH}	High Level Enable Voltage	V _{CC} = 5.5V, I _F = 10mA	Single Channel	2.0		V
V _{EL}	Low Level Enable Voltage	V _{CC} = 5.5V, I _F = 10mA ⁽²⁾	Single Channel		0.8	V

Switching Characteristics (T_A = -40°C to +85°C, V_{CC} = 5 V, I_F = 7.5 mA unless otherwise specified.)

Symbol	AC Characteristics	Test Conditions	Device	Min.	Typ.	Max.	Unit
T _{PLH}	Propagation Delay Time to Output High Level	R _L = 350Ω, C _L = 15pF ⁽³⁾ (Fig. 20) T _A = 25°C	All	20		75 100	ns
T _{PHL}	Propagation Delay Time to Output Low Level	R _L = 350Ω, C _L = 15pF ⁽⁴⁾ (Fig. 20) T _A = 25°C	All	25		75 100	ns
T _{PHL} - T _{PLH}	Pulse Width Distortion	R _L = 350Ω, C _L = 15pF (Fig. 20)	All			35	ns
t _r	Output Rise Time (10-90%)	R _L = 350Ω, C _L = 15pF ⁽⁵⁾ (Fig. 20)	Single Ch		50		ns
			Dual Ch		17		
t _f	Output Fall Time (90-10%)	R _L = 350Ω, C _L = 15pF ⁽⁶⁾ (Fig. 20)	Single Ch		12		ns
			Dual Ch		5		
t _{ELH}	Enable Propagation Delay Time to Output High Level	I _F = 7.5mA, V _{EH} = 3.5V, R _L = 350Ω, C _L = 15pF ⁽⁷⁾ (Fig. 21)	HCPL0600 HCPL0601 HCPL0611		20		ns
t _{EHL}	Enable Propagation Delay Time to Output Low Level	I _F = 7.5mA, V _{EH} = 3.5V, R _L = 350Ω, C _L = 15 pF ⁽⁸⁾ (Fig. 21)	HCPL0600 HCPL0601 HCPL0611		20		ns
ICM _H	Common Mode Transient Immunity (at Output High Level)	R _L = 350Ω, T _A = 25°C, I _F = 0mA, V _{OH} (Min.) = 2.0 V ⁽⁹⁾ (Fig. 22, 23)	V _{CM} = 10V V _{CM} = 50V V _{CM} = 1,000V	HCPL0600 HCPL0637 HCPL0601 HCPL0638 HCPL0611 HCPL0639			V/μs
ICM _L	Common Mode Transient Immunity (at Output Low Level)	R _L = 350Ω, T _A = 25°C, I _F = 7.5mA, V _{OL} (Max.) = 0.8 V ⁽¹⁰⁾ (Fig. 22, 23)	V _{CM} = 10V V _{CM} = 50V V _{CM} = 1,000V	HCPL0600 HCPL0637 HCPL0601 HCPL0638 HCPL0611 HCPL0639			V/μs

Transfer Characteristics ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise specified.)

Symbol	DC Characteristics	Test Conditions	Min.	Typ.*	Max.	Unit
I_{OH}	High Level Output Current	$V_{CC} = 5.5\text{V}$, $V_O = 5.5\text{V}$, $I_F = 250\mu\text{A}$, $V_E = 2.0\text{V}^{(2)}$			100	μA
V_{OL}	Low Level Output Voltage	$V_{CC} = 5.5\text{V}$, $I_F = 5\text{mA}$, $V_E = 2.0\text{V}$, $I_{OL} = 13\text{mA}^{(2)}$			0.6	V
I_{FT}	Input Threshold Current	$V_{CC} = 5.5\text{V}$, $V_O = 0.6\text{V}$, $V_E = 2.0\text{V}$, $I_{OL} = 13\text{mA}$			5	mA

Isolation Characteristics ($T_A = -40^\circ\text{C}$ to $+85^\circ\text{C}$ unless otherwise specified.)

Symbol	Characteristics	Test Conditions	Min.	Typ.*	Max.	Unit
I_{I-O}	Input-Output Insulation Leakage Current	Relative humidity = 45%, $T_A = 25^\circ\text{C}$, $t = 5\text{s}$, $V_{I-O} = 3000\text{VDC}^{(11)}$			1.0*	μA
V_{ISO}	Withstand Insulation Test Voltage	$R_H < 50\%$, $T_A = 25^\circ\text{C}$, $I_{I-O} \leq 2\mu\text{A}$, $t = 1\text{min.}^{(11)}$	3750			V_{RMS}
R_{I-O}	Resistance (Input to Output)	$V_{I-O} = 500\text{V}^{(11)}$		10^{12}		Ω
C_{I-O}	Capacitance (Input to Output)	$f = 1\text{MHz}^{(11)}$		0.6		pF

*All typical values are at $V_{CC} = 5\text{V}$, $T_A = 25^\circ\text{C}$

Notes:

1. The V_{CC} supply to each optoisolator must be bypassed by a $0.1\mu\text{F}$ capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package V_{CC} and GND pins of each device.
2. Enable Input – No pull up resistor required as the device has an internal pull up resistor.
3. t_{PLH} – Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
4. t_{PHL} – Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
5. t_r – Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
6. t_f – Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
7. t_{ELH} – Enable input propagation delay is measured from the 1.5V level on the HIGH to LOW transition of the input voltage pulse to the 1.5V level on the LOW to HIGH transition of the output voltage pulse.
8. t_{EHL} – Enable input propagation delay is measured from the 1.5V level on the LOW to HIGH transition of the input voltage pulse to the 1.5V level on the HIGH to LOW transition of the output voltage pulse.
9. CM_H – The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the high state (i.e., $V_{OUT} > 2.0\text{V}$). Measured in volts per microsecond ($\text{V}/\mu\text{s}$).
10. CM_L – The maximum tolerable rate of fall of the common mode voltage to ensure the output will remain in the low output state (i.e., $V_{OUT} < 0.8\text{V}$). Measured in volts per microsecond ($\text{V}/\mu\text{s}$).
11. Device considered a two-terminal device: Pins 1, 2, 3 and 4 shorted together, and Pins 5, 6, 7 and 8 shorted together.

Typical Performance Curves (HCPL0600, HCPL0601 and HCPL0611 only)

Fig. 1 Forward Current vs. Input Forward Voltage

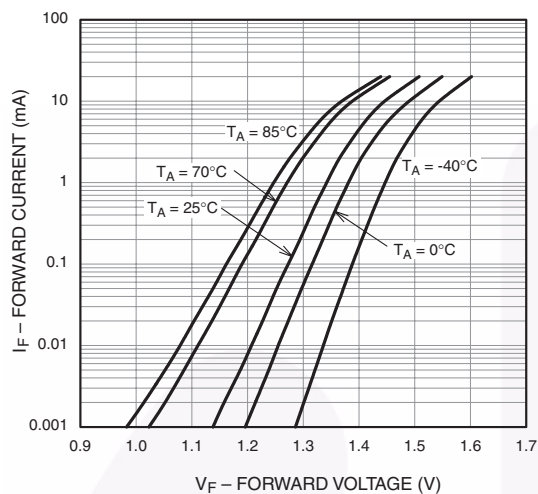


Fig. 2 Output Voltage vs. Forward Current

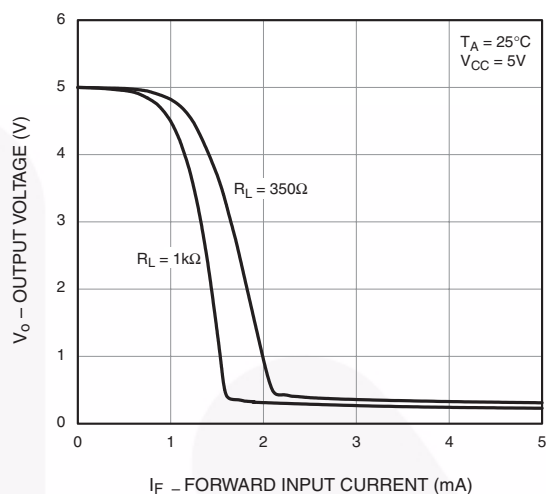


Fig. 3 Input Threshold Current vs. Temperature

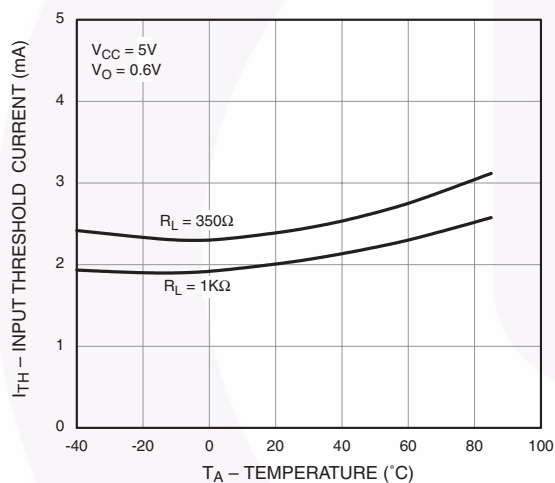
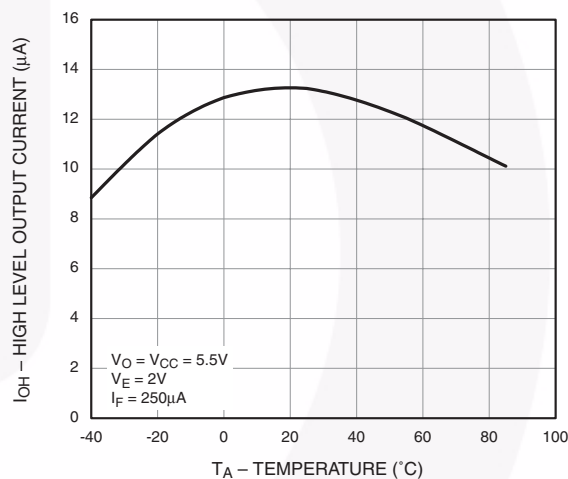


Fig. 4 High Level Output Current vs. Temperature



Typical Performance Curves (HCPL0600, HCPL0601 and HCPL0611 only)

Fig. 5 Low Level Output Voltage vs. Temperature

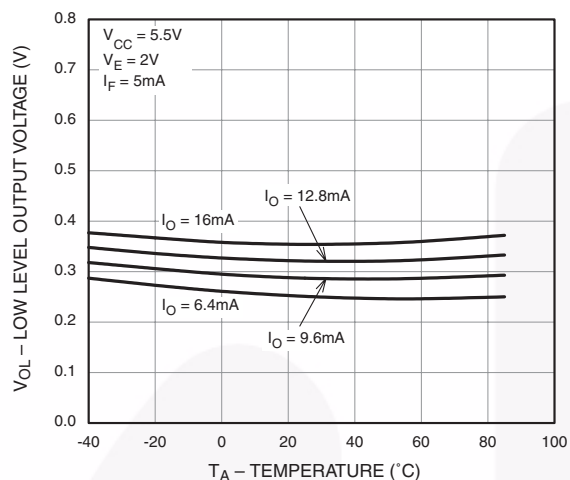


Fig. 6 Low Level Output Current vs. Temperature

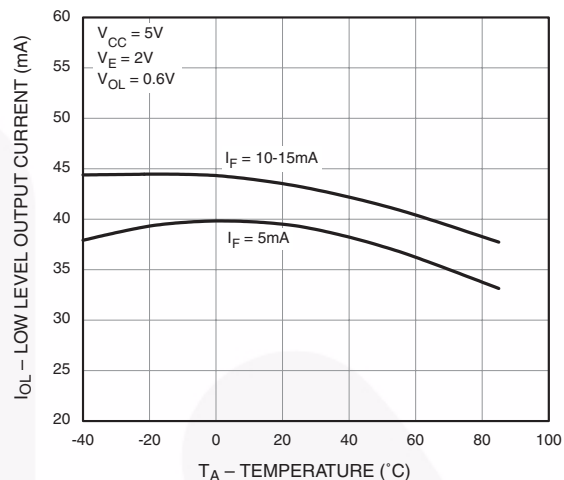


Fig. 7 Propagation Delay vs. Temperature

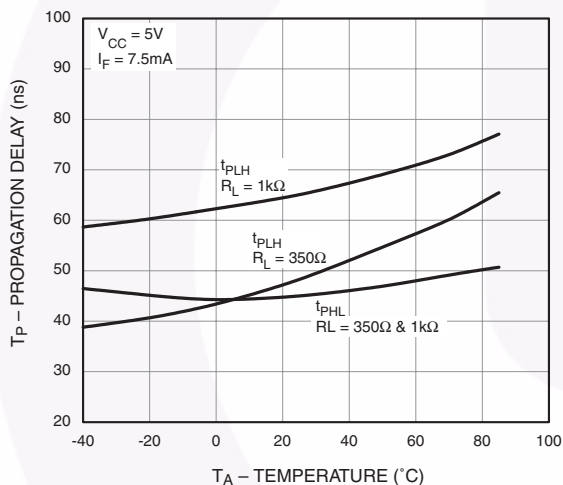
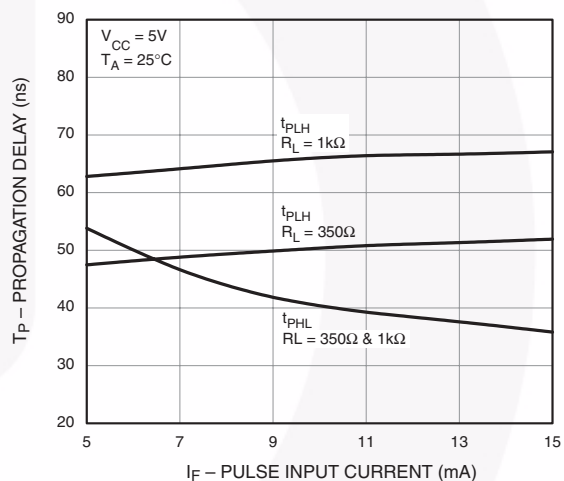


Fig. 8 Propagation Delay vs. Pulse Input Current



Typical Performance Curves (HCPL0600, HCPL0601 and HCPL0611 only)

Fig. 9 Typical Enable Propagation Delay vs. Temperature

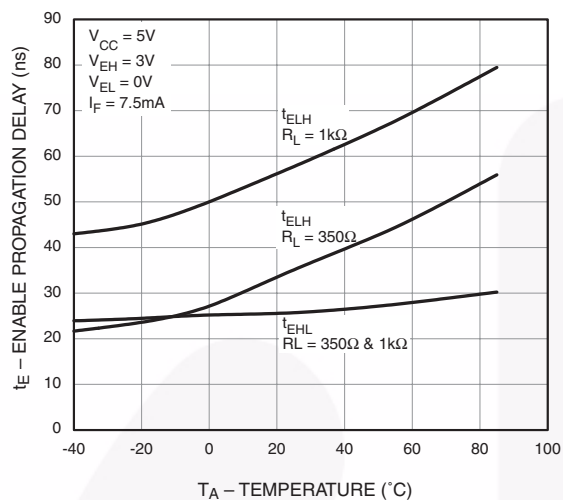


Fig. 10 Typical Rise and Fall Time vs. Temperature

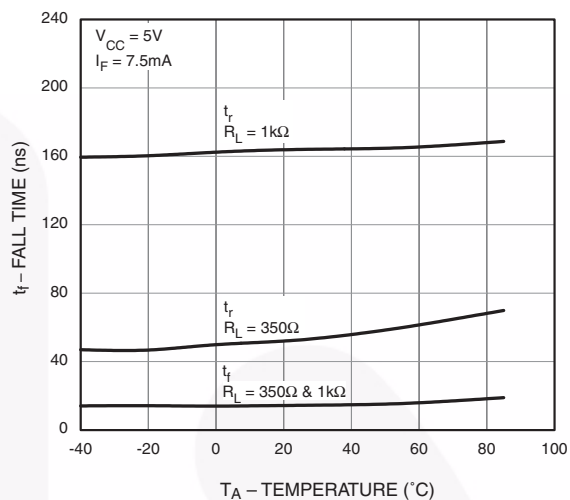
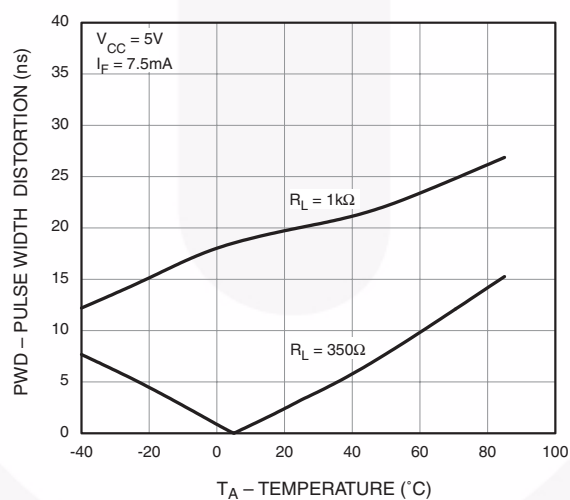


Fig. 11 Typical Pulse Width Distortion vs. Temperature



Typical Performance Curves (HCPL0637, HCPL0638 and HCPL0639 only)

Fig. 12 Input Forward Current vs. Forward Voltage

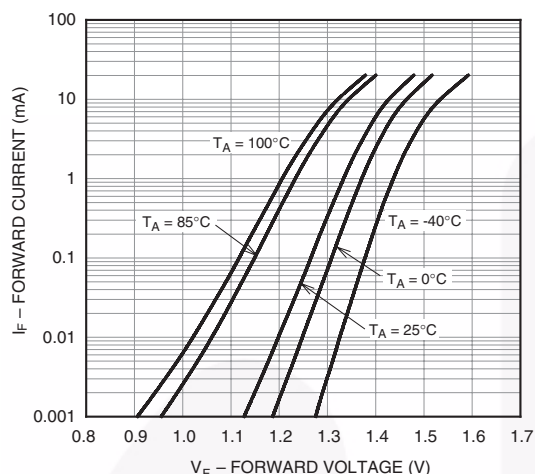


Fig. 13 Input Threshold Current vs. Ambient Temperature

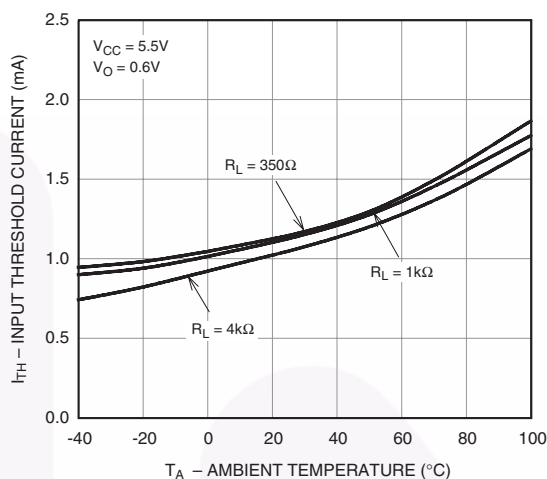


Fig. 14 High Level Output Current vs. Ambient Temperature

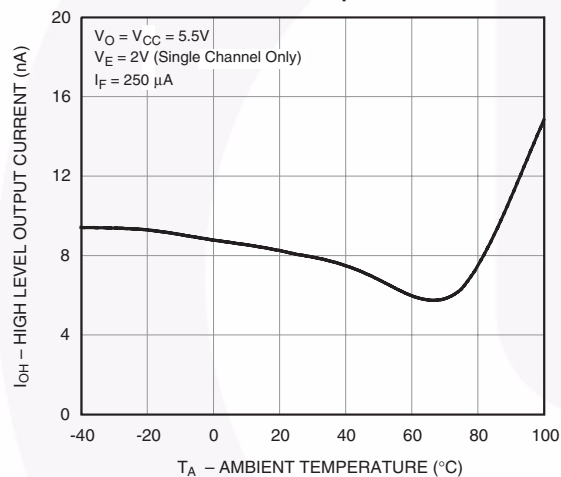


Fig. 15 Low Level Output Current vs. Ambient Temperature

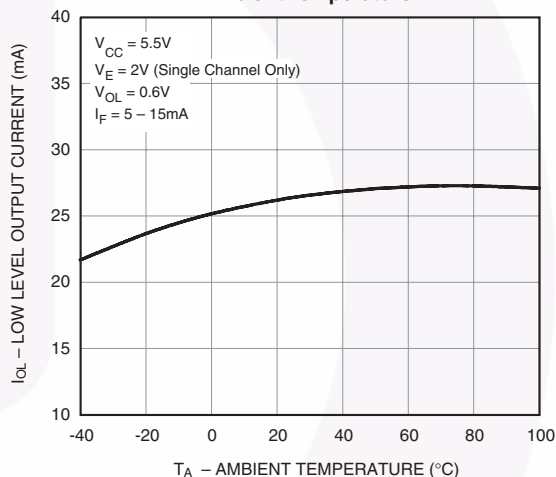


Fig. 16 Low Level Output Voltage vs. Ambient Temperature

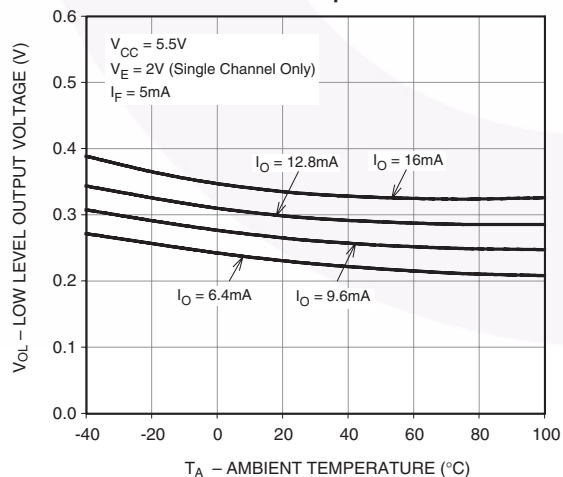
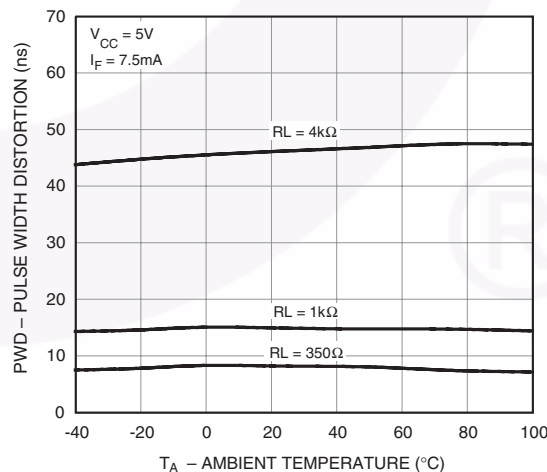


Fig. 17 Pulse Width Distortion vs. Ambient Temperature



Typical Performance Curves (HCPL0637, HCPL0638 and HCPL0639 only)

Fig. 18 Propagation Delay vs. Ambient Temperature

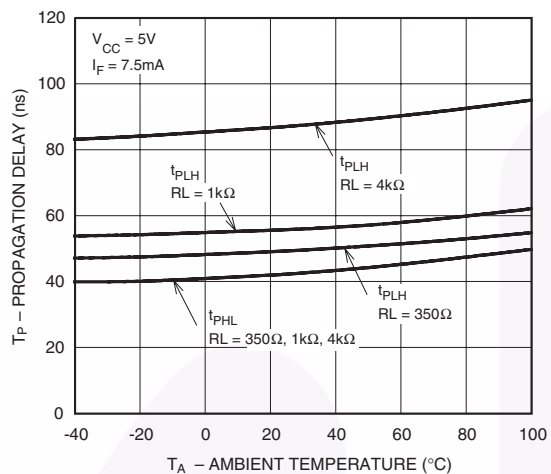
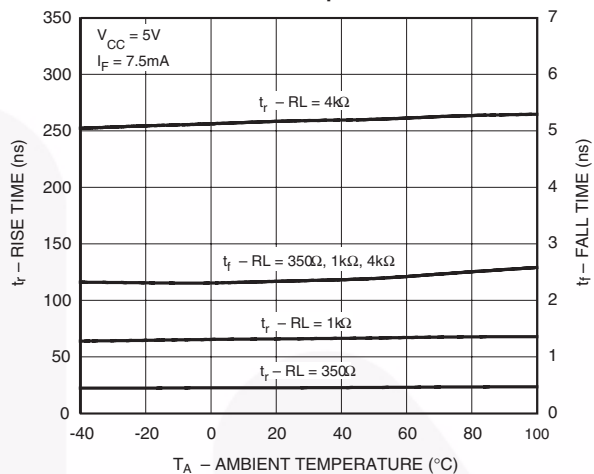


Fig. 19 Rise and Fall Times vs. Ambient Temperature



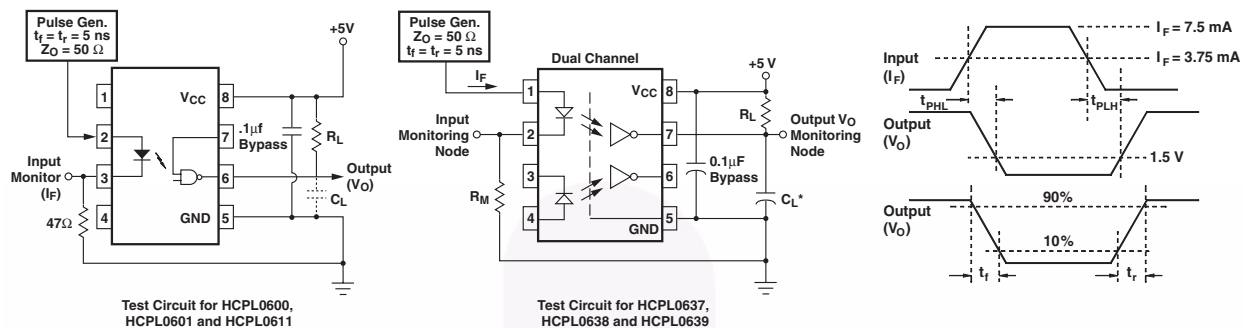


Fig. 20 Test Circuit and Waveforms for t_{PLH} , t_{PHL} , t_r and t_f .

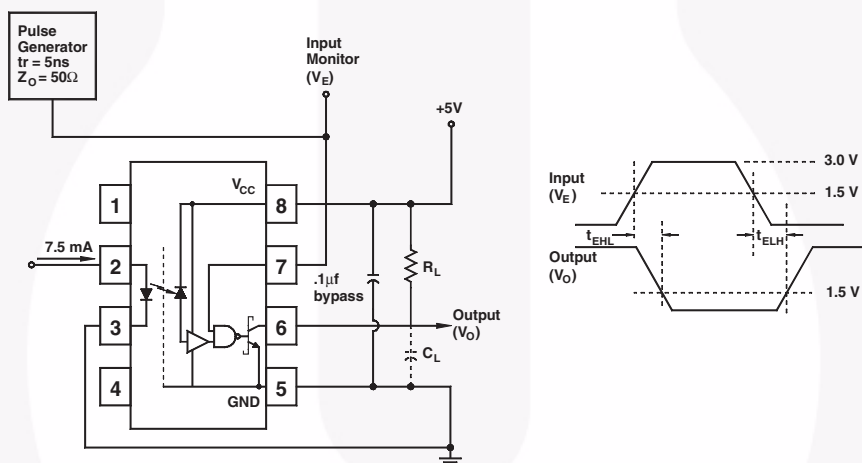
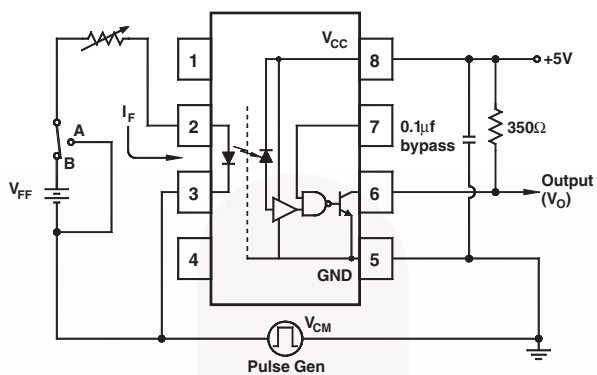


Fig. 21 Test Circuit t_{EHL} and t_{ELH} .



Test Circuit for HCPL0600, HCPL0601, and HCPL0611

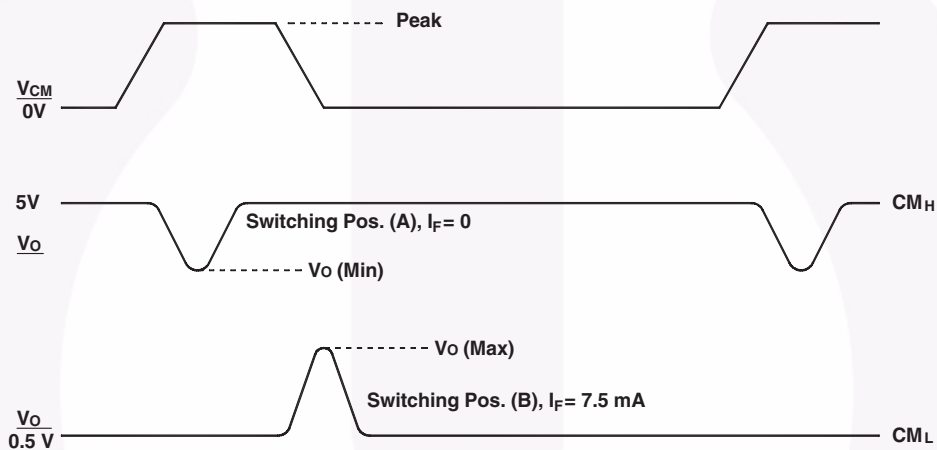
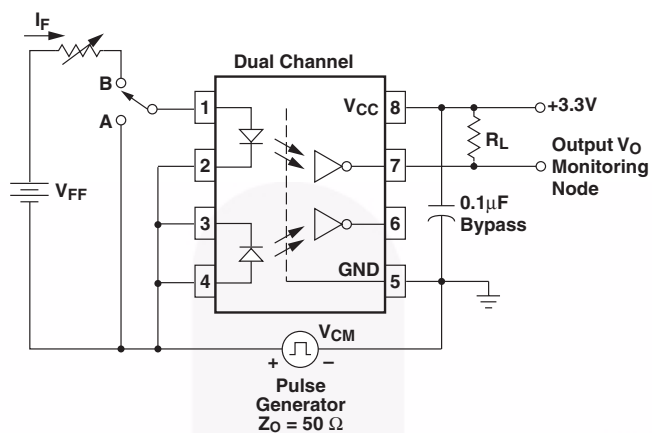


Fig. 22 Test Circuit Common Mode Transient Immunity (HCPL0600, HCPL0601 and HCPL0611)



Test Circuit for HCPL0637, HCPL0638 and HCPL0639

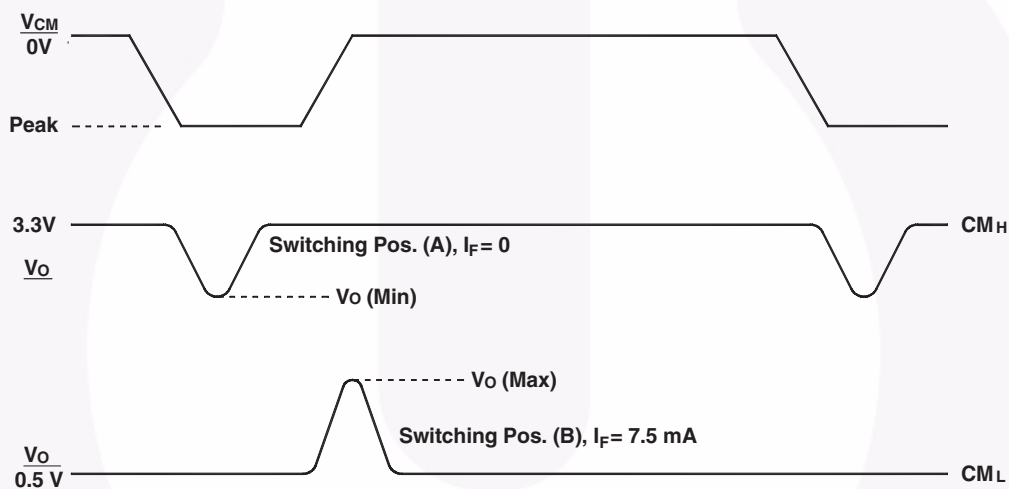
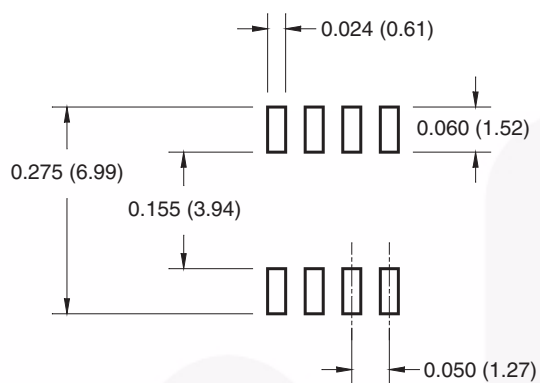


Fig. 23 Test Circuit Common Mode Transient Immunity (HCPL0637, HCPL0638 and HCPL0639)

8-Pin Small Outline

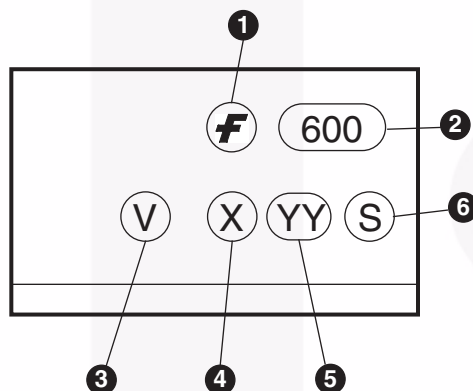


Ordering Information

Option	Order Entry Identifier	Description
No Suffix	HCPL0600	Shipped in tubes (50 units per tube)
V*	HCPL0600V	IEC60747-5-2 approval
R2	HCPL0600R2	Tape and Reel (2500 units per reel)
R2V*	HCPL0600R2V	IEC60747-5-2 approval, Tape and Reel (2500 units per reel)

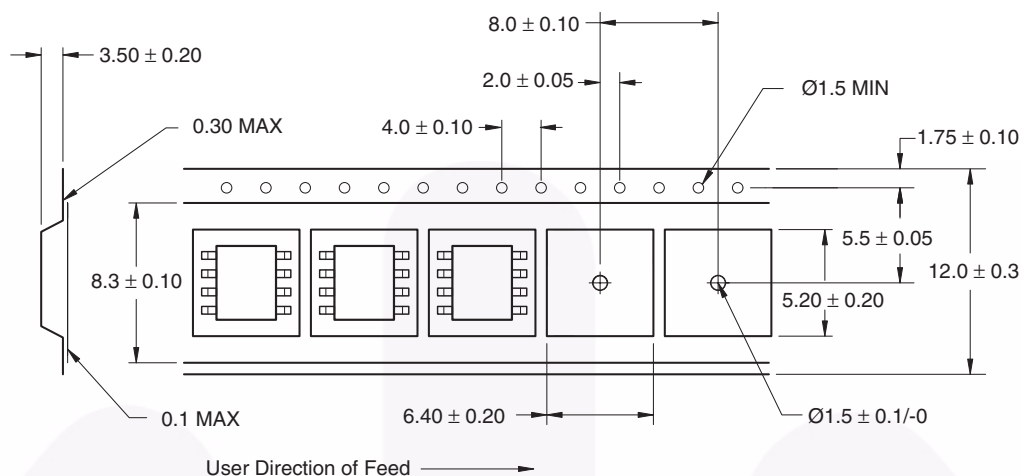
*Available for HCPL0600, HCPL0601, HCPL0611 only.

Marking Information

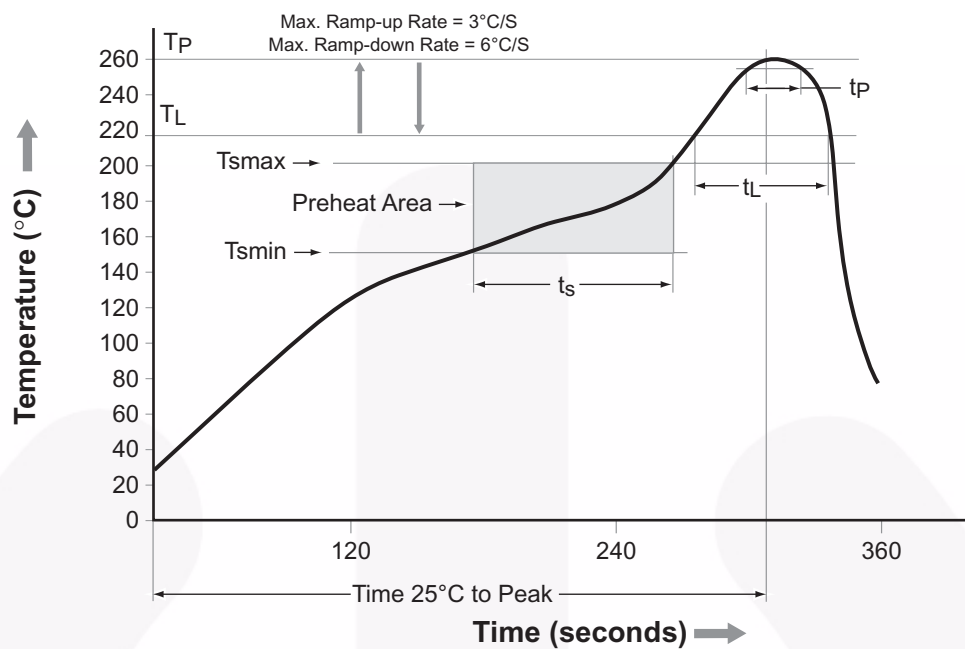


Definitions	
1	Fairchild logo
2	Device number
3	VDE mark indicates IEC60747-5-2 approval (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code, e.g., '3'
5	Two digit work week ranging from '01' to '53'
6	Assembly package code

Carrier Tape Specifications



Reflow Profile

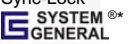


Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmmin to Tsmax)	60–120 seconds
Ramp-up Rate (tL to tp)	3°C/second max.
Liquidous Temperature (TL)	217°C
Time (tL) Maintained Above (TL)	60–150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (tp) within 5°C of 260°C	30 seconds
Ramp-down Rate (TP to TL)	6°C/second max.
Time 25°C to Peak Temperature	8 minutes max.



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EfficientMax™	ISOPLANAR™	Saving our world, 1mW/W/kW at a time™	TinyPWM™
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	MicroFET™	SPM®	TRUECURRENT™*
Fairchild®	MicroPak™	STEALTH™	µSerDes™
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FAST®	OPTOLOGIC®	SuperSOT™.8	UniFET™
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2. A critical component in any component of a life support, device, or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

ANTI-COUNTERFEITING POLICY

Fairchild Semiconductor Corporation's Anti-Counterfeiting Policy. Fairchild's Anti-Counterfeiting Policy is also stated on our external website, www.fairchildsemi.com, under Sales Support.

Counterfeiting of semiconductor parts is a growing problem in the industry. All manufacturers of semiconductor products are experiencing counterfeiting of their parts. Customers who inadvertently purchase counterfeit parts experience many problems such as loss of brand reputation, substandard performance, failed applications, and increased cost of production and manufacturing delays. Fairchild is taking strong measures to protect ourselves and our customers from the proliferation of counterfeit parts. Fairchild strongly encourages customers to purchase Fairchild parts either directly from Fairchild or from Authorized Fairchild Distributors who are listed by country on our web page cited above. Products customers buy either from Fairchild directly or from Authorized Fairchild Distributors are genuine parts, have full traceability, meet Fairchild's quality standards for handling and storage and provide access to Fairchild's full range of up-to-date technical and product information. Fairchild and our Authorized Distributors will stand behind all warranties and will appropriately address any warranty issues that may arise. Fairchild will not provide any warranty coverage or other assistance for parts bought from Unauthorized Sources. Fairchild is committed to combat this global problem and encourage our customers to do their part in stopping this practice by buying direct or from authorized distributors.

PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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